

SPDT SWITCH GaAs MMIC

■ GENERAL DESCRIPTION

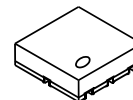
NJG1635HB6 is a GaAs SPDT switch IC suited for antenna switch of cellular phone.

This switch has many features such as high power handling, low insertion loss, high isolation and low operating current.

This device includes logic decoder function, and can be operated by single bit control signal from 1.3V of logical high voltage.

The ultra-small & ultra-thin USB6-B6 package is adopted.

■ PACKAGE OUTLINE



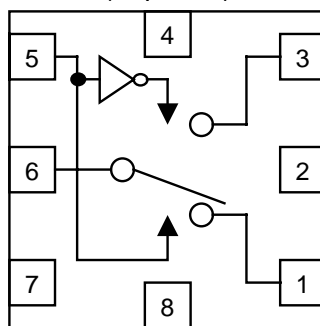
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■ FEATURES

- Single bit low voltage control +1.3V min. for logical high
- Operation supply voltage +2.5~+4.5V
- Low insertion loss 0.30dB typ. @f=0.9GHz, P_{IN}=30dBm, V_{DD}=2.7V
0.35dB typ. @f=1.9GHz, P_{IN}=30dBm, V_{DD}=2.7V
- High isolation 35dB typ. @f=0.9/1.9GHz, P_{IN}=30dBm, V_{DD}=2.7V
- High power handling P_{-0.2dB}=33.5dBm min. @V_{DD}=2.7V
- Small & thin package USB8-B6 (Package size: 1.5 x 1.5 x 0.55mm)

■ PIN CONFIGURATION

USB8-B6 Type
(Top view)



Pin connection

1. P1
2. GND
3. P2
4. GND
5. VCTL
6. PC
7. VDD
8. GND

■ TRUTH TABLE

Control Voltage: "H"=V_{CTL (H)}, "L"=V_{CTL (L)}

VCTL	PATH
H	P1-PC
L	P2-PC

NOTE: Please note that any information on this catalog will be subject to change.

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■ ABSOLUTE MAXIMUM RATINGS

$T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\Omega$

PARAMETER	SYMBOL	CONDITIONS	CONDITIONS	UNITS
RF Input Power	P_{IN}	$V_{DD}=2.7\text{V}$, $V_{CTL}=0/1.8\text{V}$	35	dBm
Supply Voltage	V_{DD}	VDD terminal	5.0	V
Control Voltage	V_{CTL}	VCTL terminal	5.0	V
Power Dissipation	P_D	on PCB board	160	mW
Operating Temp.	T_{opr}		-40~+85	$^{\circ}\text{C}$
Storage Temp.	T_{stg}		-55~+150	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS

General conditions: $V_{DD}=2.7\text{V}$, $V_{CTL(L)}=0\text{V}$, $V_{CTL(H)}=1.8\text{V}$, $Z_s=Z_l=50\Omega$, $T_a=+25^{\circ}\text{C}$

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Voltage	V_{DD}		2.5	2.7	4.5	V
Operating Current	I_{DD}	$P_{IN}=30\text{dBm}$	-	25	50	μA
Control Voltage (LOW)	$V_{CTL(L)}$		0	-	0.4	V
Control Voltage (HIGH)	$V_{CTL(H)}$		1.3	1.8	4.5	V
Control Current	I_{CTL}		-	5	10	μA
Insertion Loss 1	LOSS1	$f=0.9\text{GHz}$, $P_{IN}=30\text{dBm}$	-	0.30	0.45	dB
Insertion Loss 2	LOSS2	$f=1.9\text{GHz}$, $P_{IN}=30\text{dBm}$	-	0.35	0.50	dB
Isolation 1	ISL1	$f=0.9\text{GHz}$, $P_{IN}=30\text{dBm}$	32	35	-	dB
Isolation 2	ISL2	$f=1.9\text{GHz}$, $P_{IN}=30\text{dBm}$	30	35	-	dB
0.2dB Compression input power	$P_{-0.2\text{dB}}$	$f=1.9\text{GHz}$	33.5	-	-	dBm
VSWR (PC, P1, P2)	VSWR	$f=1.9\text{GHz}$, ON State	-	1.2	1.4	
Switching time	T_{sw}	PC-P1, PC-P2 port switching time	-	2	5	μs

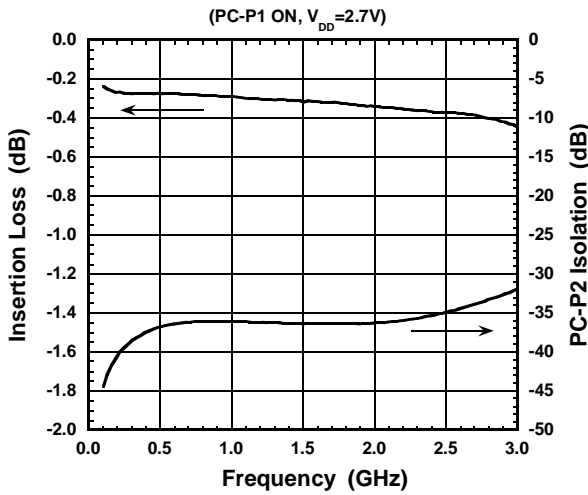
■ TERMINAL INFORMATION

No.	SYMBOL	DESCRIPTION
1	P1	This port is connected to PC port by control voltage of +1.3~4.5V($V_{CTL(H)}$) to 5th pin. An external capacitor is required to block the DC bias voltage of internal circuit.
2	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
3	P2	This port is connected to PC port by control voltage of +0.0~0.4V($V_{CTL(L)}$) to 5th pin. An external capacitor is required to block the DC bias voltage of internal circuit.
4	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
5	VCTL	Control port. This terminal is set to +1.3V~4.5V of logical high level for ON state between PC and P1 RF ports, and set to +0.0~0.4V of logical low level for ON state between PC and P2 RF ports.
6	PC	Common RF port. This PC port is connected to P1 or P2 by logical control voltage of VCTL. In order to block DC bias voltage of internal circuit, an external capacitor is required.
7	VDD	A supply voltage terminal (+2.5~+4.5V). Please place a bypass capacitor between this and GND for avoiding RF noise from outside.
8	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.

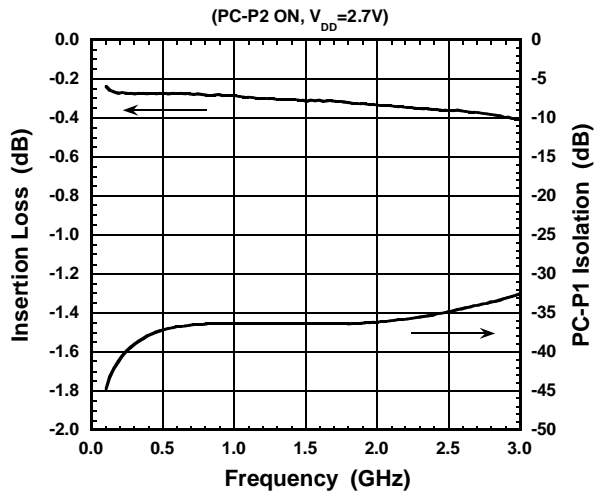
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■ ELECTRICAL CHARACTERISTICS (With Application circuit, Loss of external circuit are excluded)

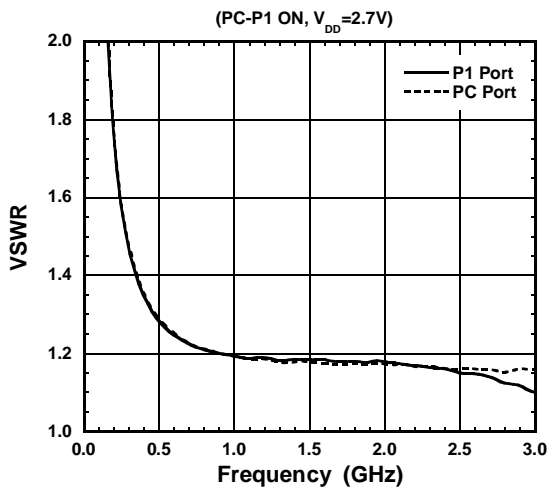
Loss, ISL vs Frequency



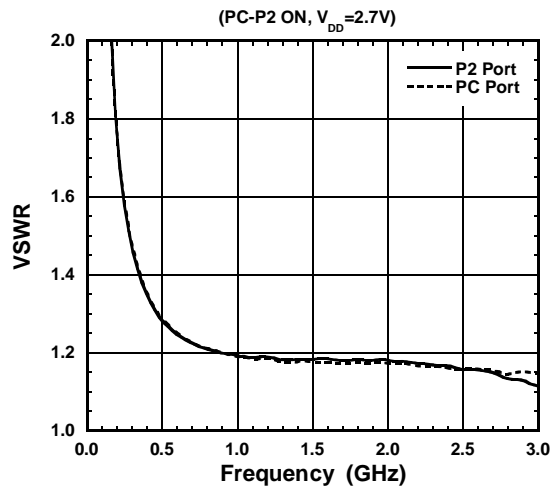
Loss, ISL vs Frequency



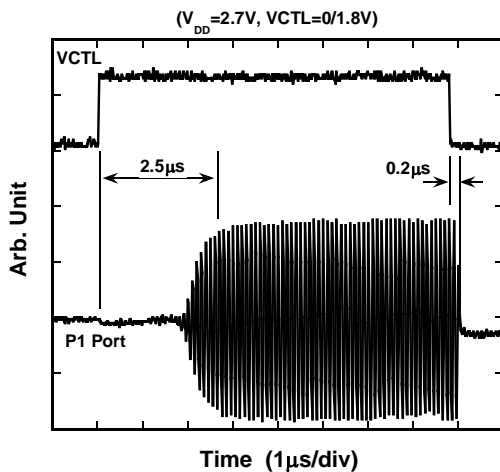
VSWR vs Frequency



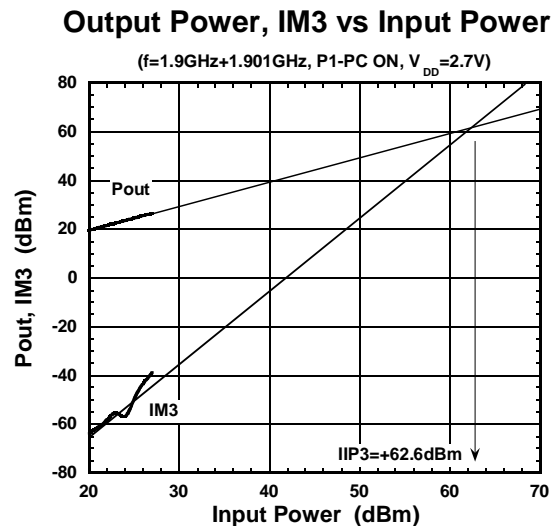
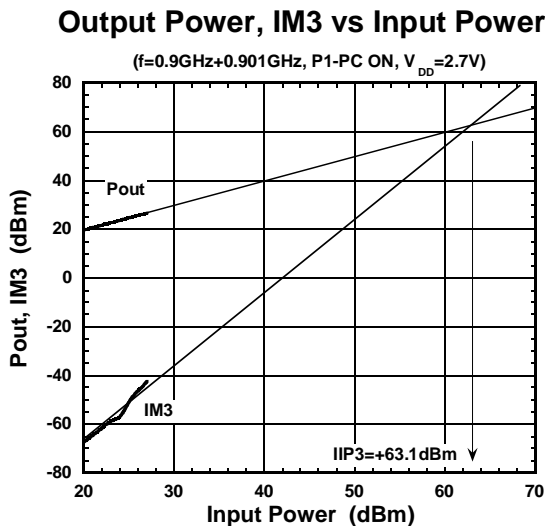
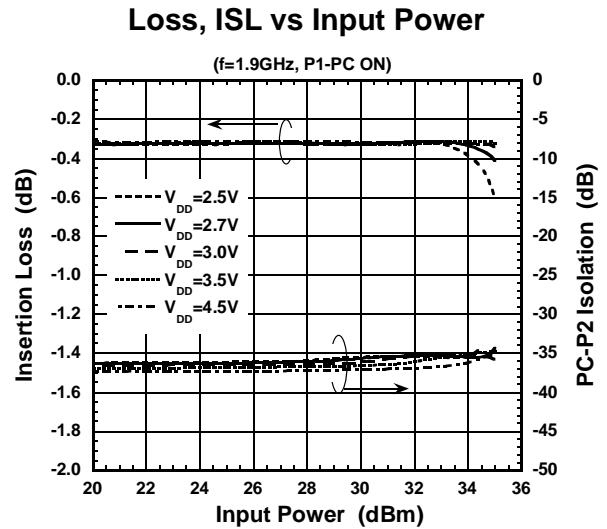
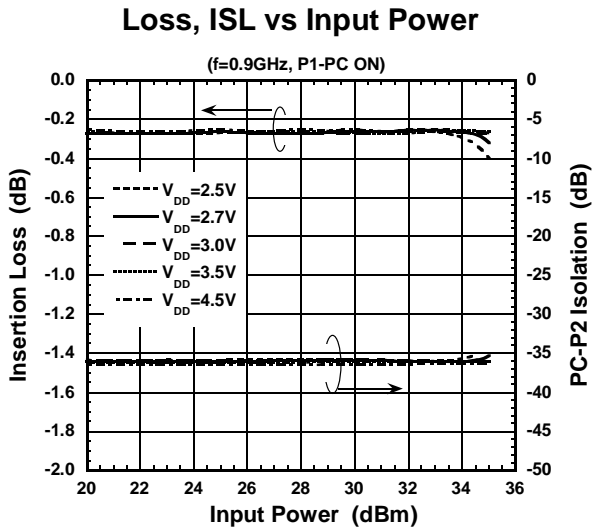
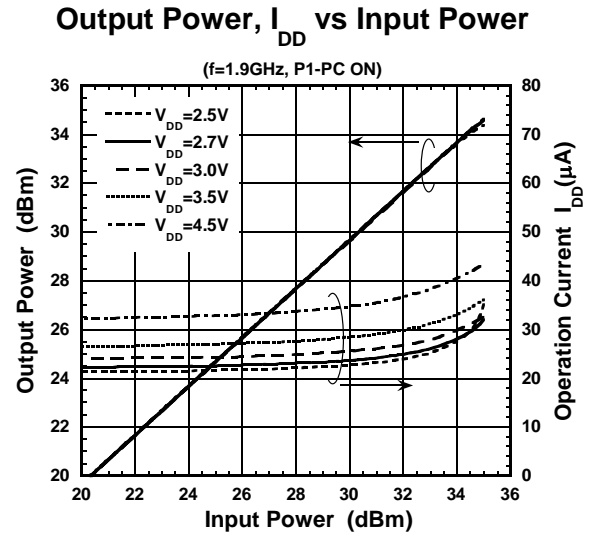
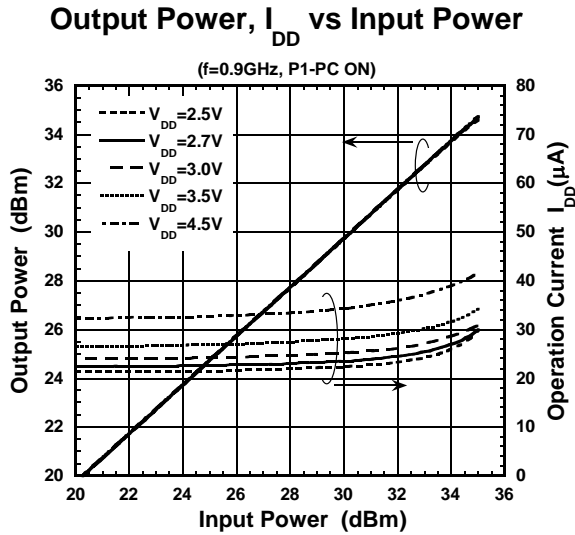
VSWR vs Frequency



Switching Time

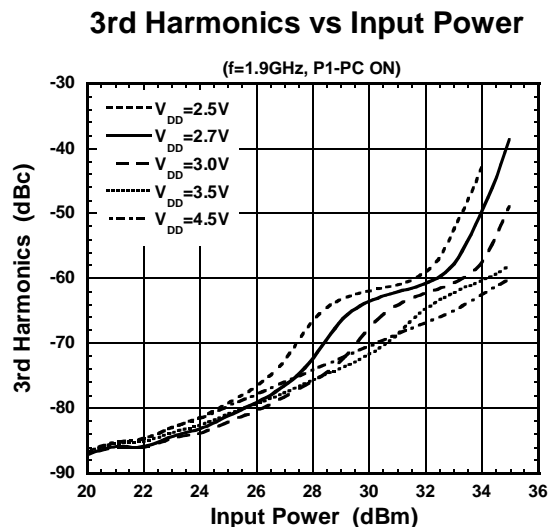
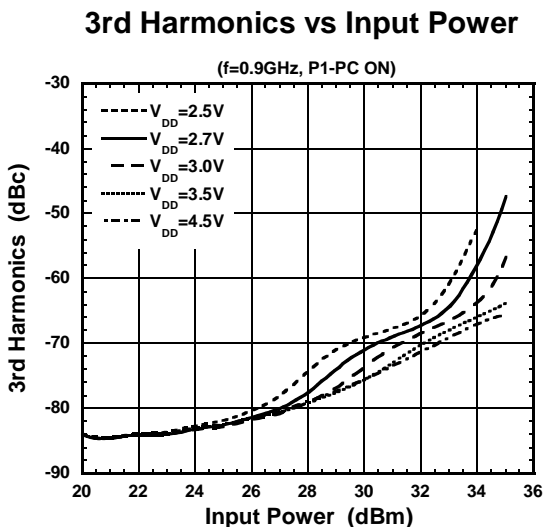
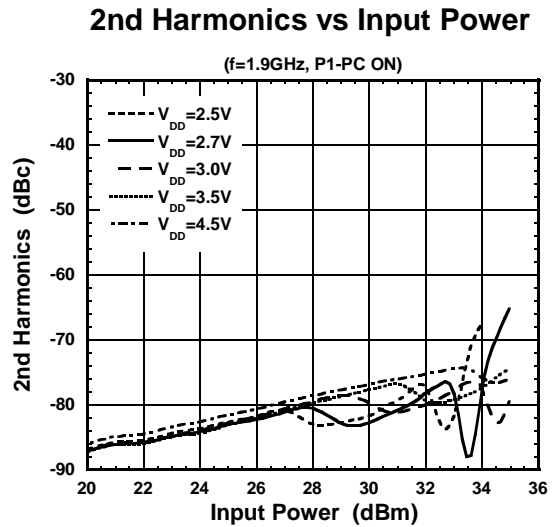
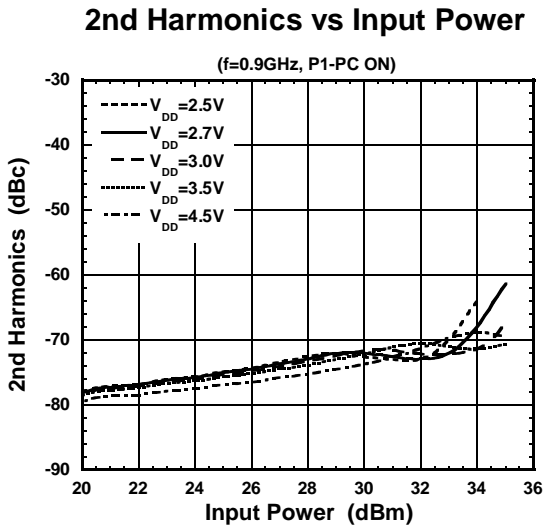
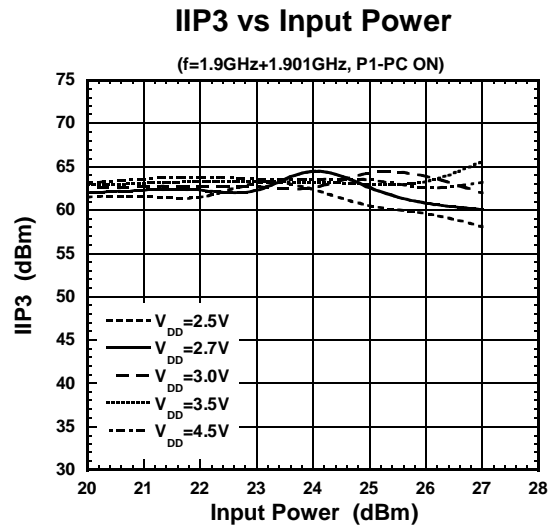
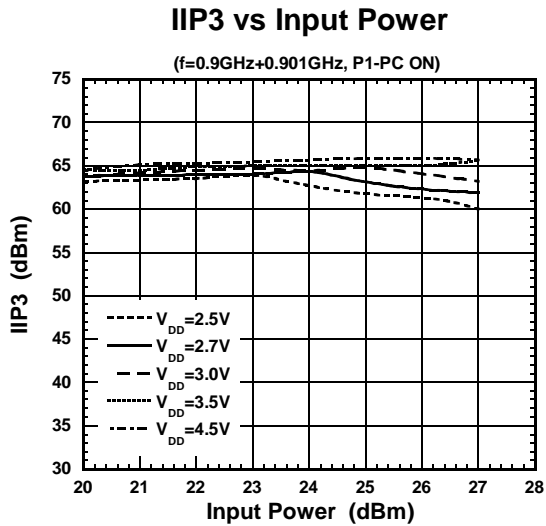


■ ELECTRICAL CHARACTERISTICS (With Application circuit, Loss of external circuit are excluded)

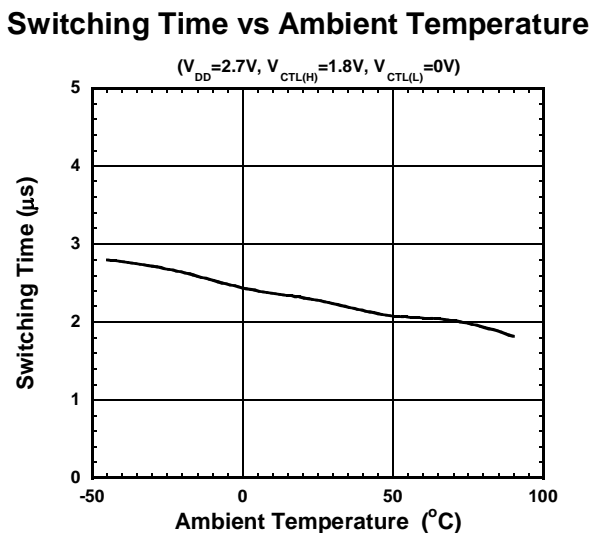
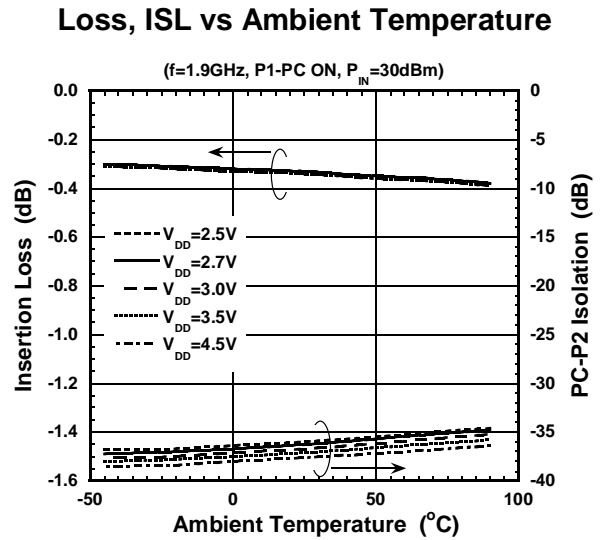
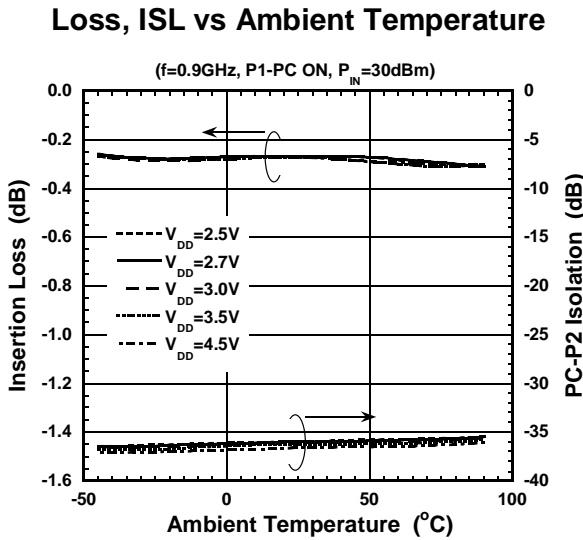
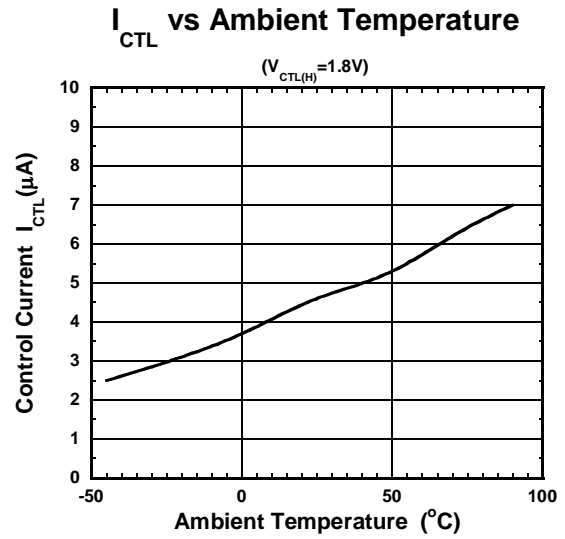
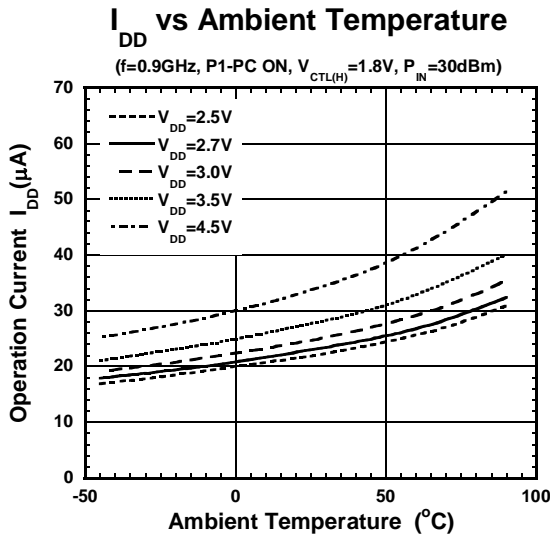


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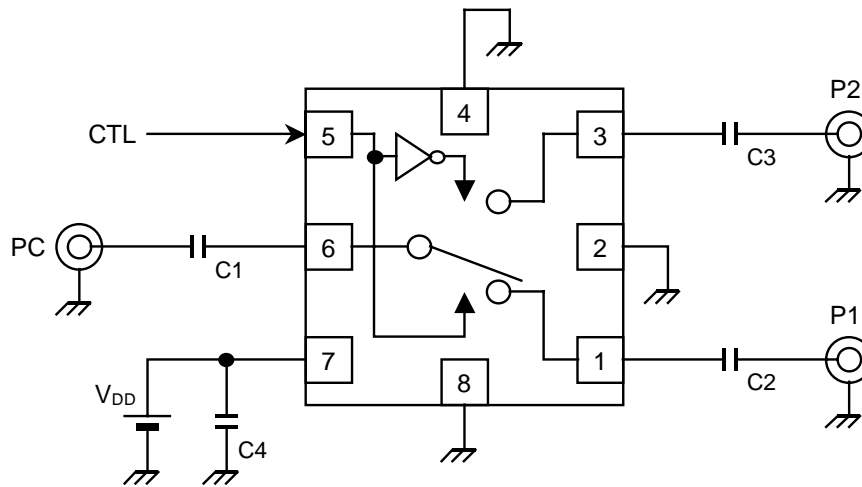


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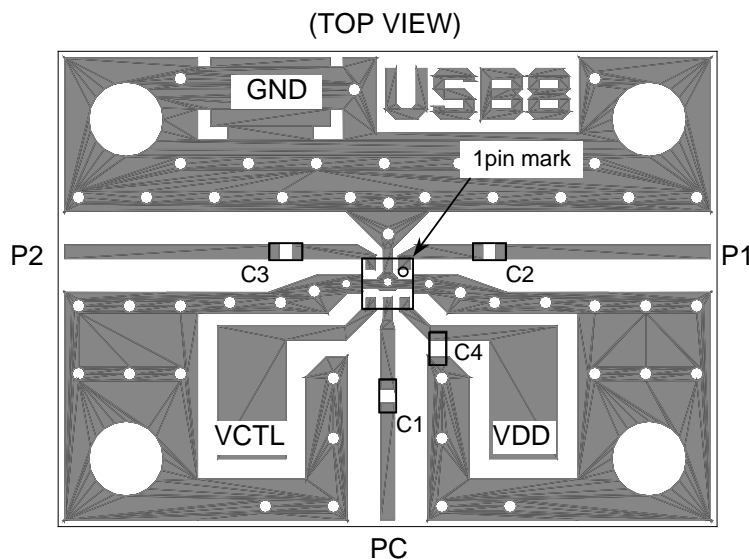
APPLICATION CIRCUIT



PARTS LIST

PART ID	Value	COMMENT
C1~C3	56pF	MURATA (GRM15)
C4	1000pF	

TEST PCB LAYOUT



PCB SIZE=19.4x14.0mm

PCB: FR-4, t=0.2mm

CAPACITOR: size 1005

STLILINE=0.4mm

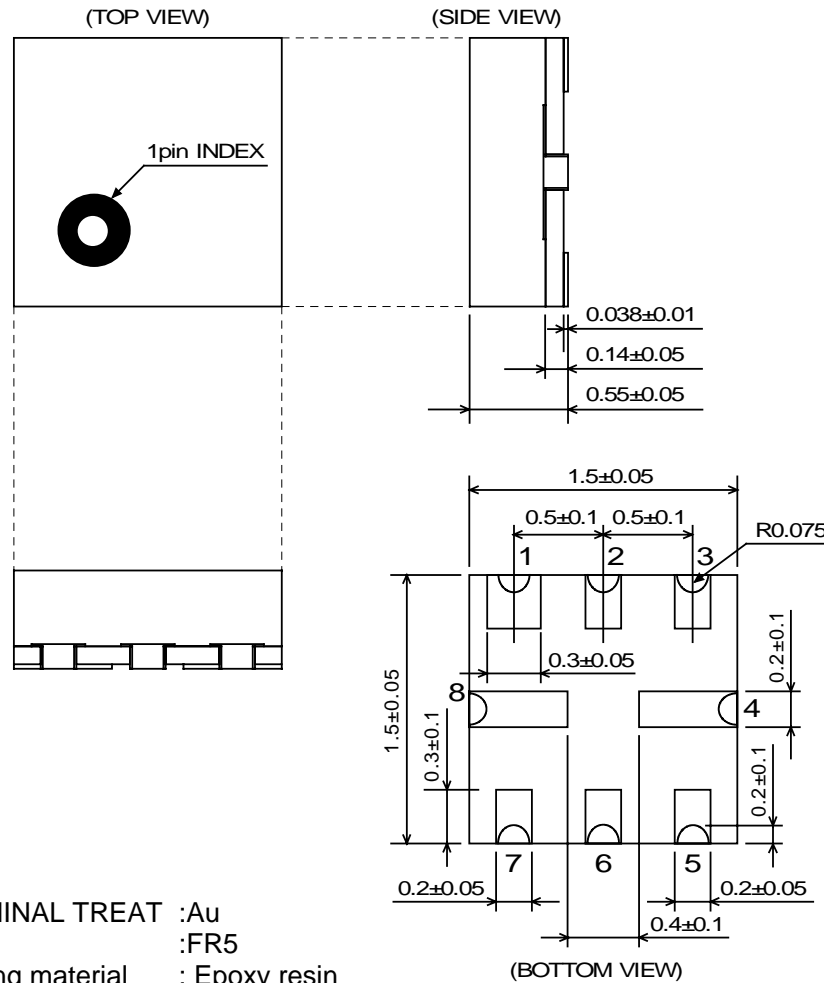
Losses of PCB, capacitors and connectors

Frequency (GHz)	Loss (dB)
0.9	0.21
1.9	0.30

PRECAUTIONS

- [1]The DC blocking capacitors have to be placed at RF terminal of P1, P2 and PC. Please choose appropriate capacitance values to the application frequency.
- [2]To reduce strip line influence on RF characteristics, please locate bypass capacitors(C4) as close as possible to each terminals.
- [3]For good isolation, the GND terminal (2nd pin) must be connected to the ground plane of substrate, and through-holes for GND should be placed near by the pin connection.

PACKAGE OUTLINE (USB8-B6)



TERMINAL TREAT :Au
 PCB :FR5
 Molding material : Epoxy resin
 UNIT :mm
 WEIGHT :4mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.